# MMBTA55L Series, MMBTA56L Series, SMMBTA56L Series

# **Driver Transistors**

# **PNP Silicon**

#### Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

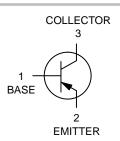


# **ON Semiconductor®**

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CASE 318 STYLE 6



#### MARKING DIAGRAM



- 2xx = Device Codex = H for MMBTA55LT1G xx = GM for MMBTA56LT1G,
  - SMMBTA56LT1G
- M = Date Code\*
- = Pb–Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage MMBTA55 MMBTA56, SMMBTA56	V <sub>CEO</sub>	-60 -80	Vdc
Collector-Base Voltage MMBTA55 MMBTA56, SMMBTA56	V <sub>CBO</sub>	-60 -80	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	-4.0	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	-500	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.

2. Alumina = 0.4  $\times$  0.3  $\times$  0.024 in. 99.5% alumina.

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#### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
$\begin{array}{l} \mbox{Collector}-\mbox{Emitter Breakdown Voltage (Note 3)} \\ (I_C = -1.0 \mbox{ mAdc, } I_B = 0) \\ \mbox{MMBTA55} \\ \mbox{MMBTA56, SMMBTA56} \end{array}$	V <sub>(BR)CEO</sub>	-60 -80		Vdc
Emitter – Base Breakdown Voltage ( $I_E = -100 \ \mu Adc, I_C = 0$ )	V <sub>(BR)EBO</sub>	-4.0	_	Vdc
Collector Cutoff Current ( $V_{CE} = -60 \text{ Vdc}, I_B = 0$ )	I <sub>CES</sub>	-	-0.1	μAdc
Collector Cutoff Current $(V_{CB} = -60 \text{ Vdc}, I_E = 0)$ MMBTA55 $(V_{CB} = -80 \text{ Vdc}, I_E = 0)$ MMBTA56, SMMBTA56	Ісво	-	-0.1 -0.1	μAdc
ON CHARACTERISTICS	·			
DC Current Gain ( $I_C = -10 \text{ mAdc}, V_{CE} = -1.0 \text{ Vdc}$ ) ( $I_C = -100 \text{ mAdc}, V_{CE} = -1.0 \text{ Vdc}$ )	h <sub>FE</sub>	100 100		-
Collector – Emitter Saturation Voltage ( $I_C = -100$ mAdc, $I_B = -10$ mAdc)	V <sub>CE(sat)</sub>	_	-0.25	Vdc

### $(I_{C} = -100 \text{ mAdc}, V_{CE} = -1.0 \text{ Vdc})$ SMALL-SIGNAL CHARACTERISTICS

Base-Emitter On Voltage

Current-Gain - Bandwidth Product (Note 4)	f <sub>T</sub>			MHz
$(I_{C} = -100 \text{ mAdc}, V_{CE} = -1.0 \text{ Vdc}, f = 100 \text{ MHz})$		50	-	

V<sub>BE(on)</sub>

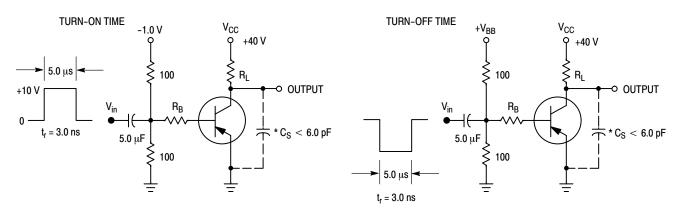
Vdc

-1.2

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2.0%.

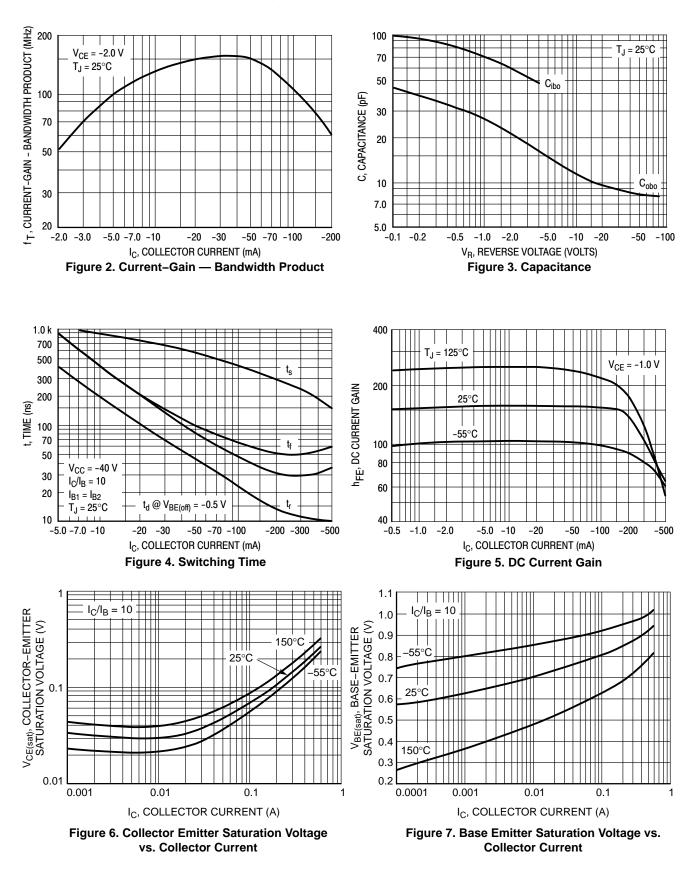
4.  $f_T$  is defined as the frequency at which  $|h_{fe}|$  extrapolates to unity.



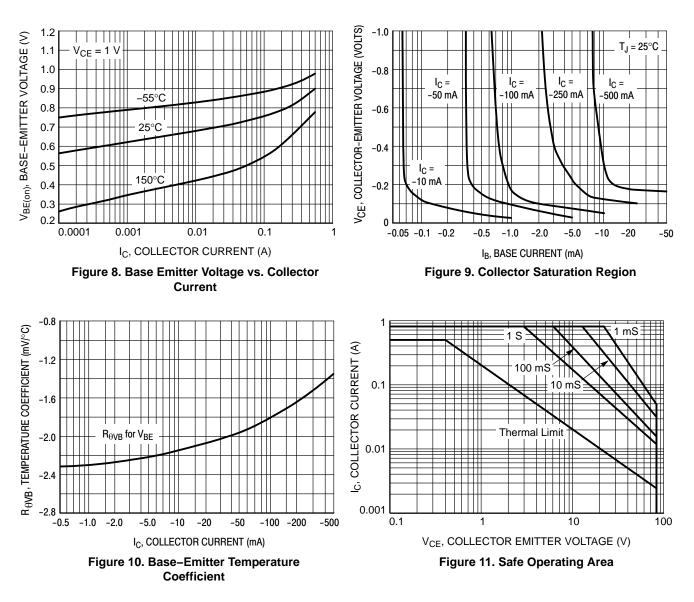
\*Total Shunt Capacitance of Test Jig and Connectors For PNP Test Circuits, Reverse All Voltage Polarities

#### Figure 1. Switching Time Test Circuits

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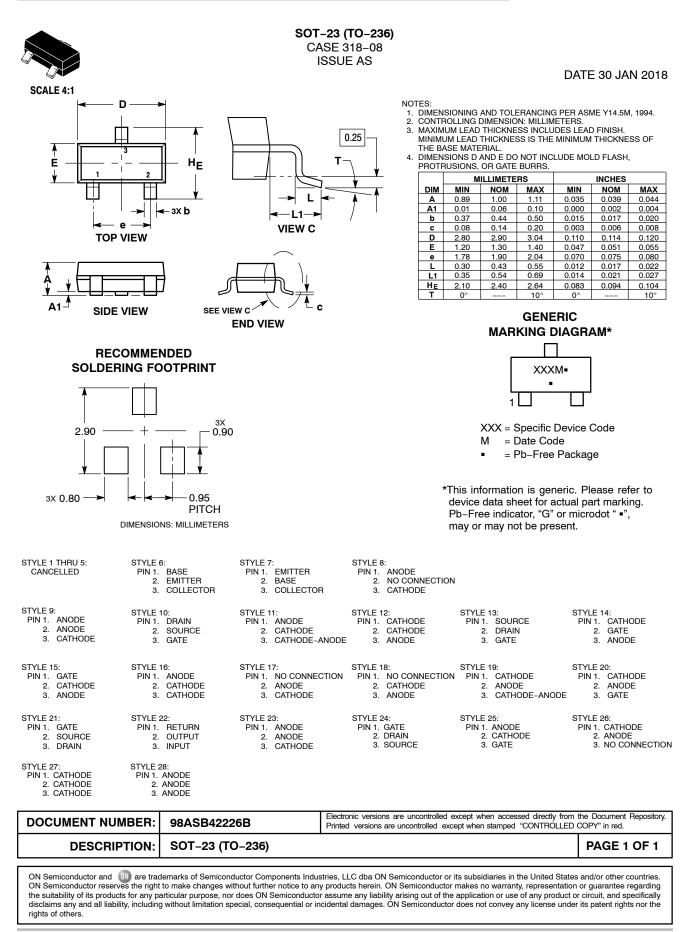


#### **ORDERING INFORMATION**

Device Order Number	Package Type	Shipping <sup>†</sup>
MMBTA55LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
MMBTA55LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel
MMBTA56LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
SMMBTA56LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
MMBTA56LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel
SMMBTA56LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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